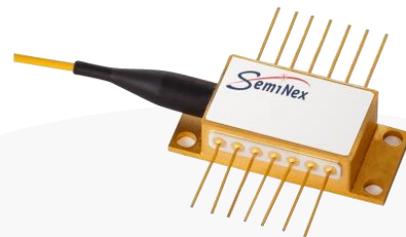


# High Power External Cavity Laser 14-pin Butterfly Narrow Linewidth Single-Frequency



## Part Number: 14BF-312-200

High Power External Cavity Laser  
14BF Narrow Linewidth Single-Frequency  
CW Wavelength at O band



## Features

- Narrow linewidth ( $\sim 10$  kHz)
- Wavelength ranges cover O-band wavelengths
- High output optical power (up to 200mw)
- Ultra-low RIN, excellent SMSR
- SemiNex ROSA and SOA Chip Inside

## Application

- Fiber optical sensing: acoustic & seismic interferometric sensing, Oil & Gas - exploration and production
- LiDAR and industrial metrology
- Optical measurements and instrumentation



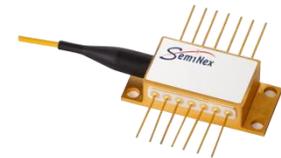
SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.

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## Specification

14BF-312-200



Optical	Symbol	Min.	Typ.	Max.	Units
Center Wavelength	$\lambda_c$		1310 or O band		nm
Linewidth (Lorentzian)	FWHM		10		kHz
Fiber Output Power	$P_f$		200		mW
Side Mode Suppression	SMSR		60		dB
Polarization Extinction Ratio	PER	20			dB
Random Intensity Noise	RIN			-145	dB/Hz
Optical Isolation	ISO		50		dB
Operating Temperature	T <sub>O</sub>	-20		60	°C
Storage Temperature	T <sub>S</sub>	-40		85	°C
Operating Humidity	%	5		85	
Parameter	Symbol	Min.	Typ.	Max.	Unit
LD Voltage	V <sub>LD</sub>		1.6	1.8	V
LD Current	I <sub>LD</sub>		150	300	mA
TEC Voltage	V <sub>TEC</sub>		1.8	2.5	V
TEC Current	I <sub>TEC</sub>		1	1.5	A
TEC Temp.	T <sub>TEC</sub>		25	50	°C
SOA Voltage	V <sub>SOA</sub>		2		V
SOA Current	I <sub>SOA</sub>		1000		mA

\*Specified values are rated at a constant heat sink temperature of 20°C.

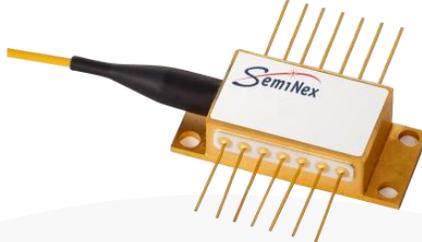
\*\*High temperature operation will reduce performance and MTTF.

Unless otherwise indicated all values are nominal.

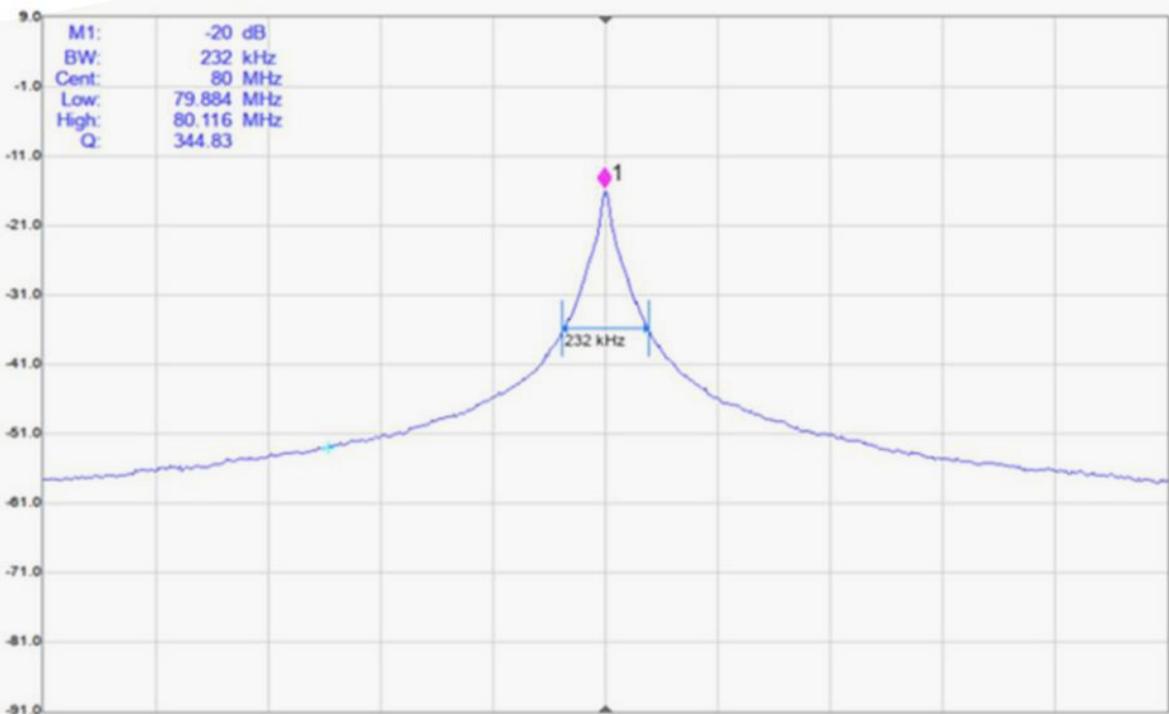
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## SemiNex Laser Diodes 14BF-312-200 Graphs & Data



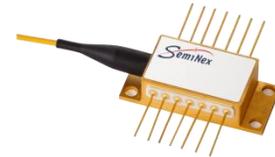
Lorentzian Linewidth (11.6kHz)



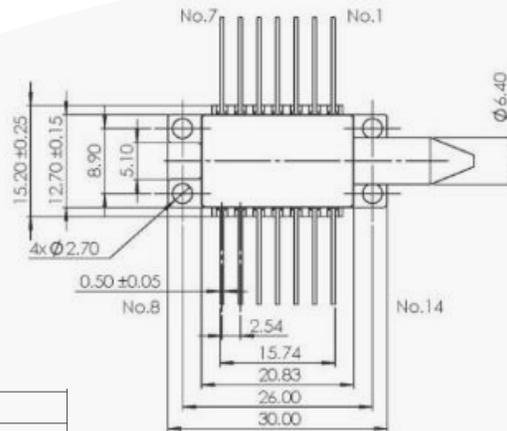
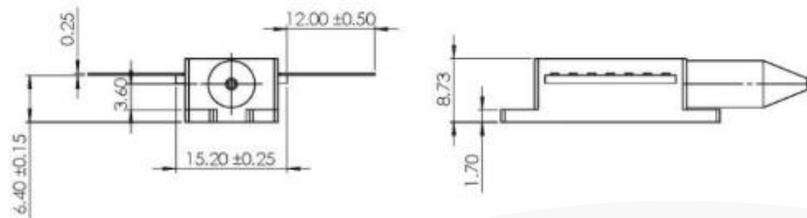
# High Power External Cavity Laser 14-pin Butterfly Narrow Linewidth Single-Frequency



## Mechanical Drawing



No.	Description	Parameter	Unit	Note
1	Fiber type	PMF $\phi$ 0.9mm red		PMF/SMF Optional
2	Fiber length	1000 $\pm$ 10	mm	
3	Connector	FC/APC		



Pinout				
1	TEC +	8	N/A	
2	NTC	9	N/A	
3	NTC	10	N/A	
4	N/A	11	SOA+	
5	LD+	12	SOA-	
6	LD-	13	Case	
7	N/A	14	TEC -	

**Warnings:**  
Make sure to wear protective goggles while operating high power laser that could be harmful to eyes. Nearby operators should wear protective goggles to avoid harms from the reflective of the laser. SemiNex reserves the right to modify this document without notice.

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